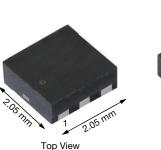
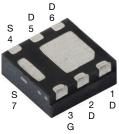
SQA446CEJW

www.vishay.com

Vishay Siliconix

Automotive N-Channel 20 V (D-S) 175 °C MOSFET





Bottom View

Marking Code: QZXXXX

PRODUCT SUMMARY V_{DS} (V) 20 $R_{DS(on)}$ (Ω) at V_{GS} = 4.5 V 0.0175 $R_{DS(on)}$ (Ω) at V_{GS} = 2.5 V 0.0240 I_D (A) 9 Configuration Single

PowerPAK[®] SC-70W-6L Single

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- Wettable flank terminals
- 100 % R_{α} and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



FREE

G Q S

N-Channel MOSFET

ORDERING INFORMATION						
	Package	PowerPAK SC-70W-6L				
	Lead (Pb)-free and halogen-free	SQA446CEJW (for detailed order number please see www.vishay.com/doc?79776)				

ABSOLUTE MAXIMUM RATING	S (T _C = 25 °C, unles	s otherwise noted)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage Gate-source voltage		V _{DS}	20	V
		V _{GS}	± 12	V
Continuous drain surrent à	T _C = 25 °C	1	9	
Continuous drain current ^a	T _C = 125 °C	ID	9	
Continuous source current (diode conductio	n) ^a	IS	9	А
Pulsed drain current ^a		I _{DM}	36	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	26	
Single pulse avalanche energy	L = 0.1 MH	E _{AS}	33.8	mJ
Maximum neuror discinction	T _C = 25 °C	PD	13.6	W
Maximum power dissipation	$T_{\rm C} = 125 \ ^{\circ}{\rm C} \qquad \qquad 4.5$	4.5	vv	
Operating junction and storage temperature	range	T _J , T _{stg}	-55 to +175	°C
Soldering recommendations (peak temperat	ure) ^{d, e}		260	C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^c	R _{thJA}	90	°C/W	
Junction-to-case (drain)		R _{thJC}	11	C/W	

Notes

a. Package limited

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

c. When mounted on 1" square PCB (FR4 material)

d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SC-70W-6L is a leadless package and features wettable flank terminals. The end of the lead terminal is plated with tin.

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

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PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static		•					
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$		20	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	: V _{GS} , I _D = 250 μΑ	0.6	1.0	1.3	v
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, $V_{GS} = \pm 12$ V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 20 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 20 V, T _J = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	V _{DS} = 20 V, T _J = 175 °C	-	-	250	
On-state drain current ^a	I _{D(on)}	V _{GS} = 4.5 V	$V_{DS} \ge 5 V$	9	-	-	Α
		V _{GS} = 4.5 V	I _D = 4.5 A	-	0.0142	0.0175	
Drain agurag an atota registance à	р	$V_{GS} = 4.5 V$	I _D = 4.5 A, T _J = 125 °C	-	-	0.0250	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V	I _D = 4.5 A, T _J = 175 °C	-	-	0.0289	Ω
		V _{GS} = 2.5 V	I _D = 3 A	-	0.0194	0.0240	
Forward transconductance b	g fs	V _{DS}	= 10 V, I _D = 4 A	-	28	-	S
Dynamic ^b						•	
Input capacitance	C _{iss}			-	649	910	
Output capacitance	Coss	$V_{GS} = 0 V$	V _{DS} = 10 V, f = 1 MHz	-	174	245	pF
Reverse transfer capacitance	C _{rss}			-	71	100	
Total gate charge ^c	Qg			-	6.5	10	
Gate-source charge ^c	Q _{gs}	V _{GS} = 4.5 V	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 8 \text{ A}$	-	1.6	-	nC
Gate-drain charge ^c	Q _{gd}			-	1.6	-	
Gate resistance	Rg		f = 1 MHz	0.5	1.0	1.5	Ω
Turn-on delay time ^c	t _{d(on)}	V_{DD} = 10 V, R _L = 4 Ω I _D \cong 2.5 A, V _{GEN} = 4.5 V, R _g = 1 Ω		-	10	16	
Rise time ^c	t _r			-	19	30	ns
Turn-off delay time ^c	t _{d(off)}			-	19	30	
Fall time ^c	t _f			-	8	15	
Source-Drain Diode Ratings and Charact	eristics ^b						
Pulsed current ^a	I _{SM}			-	-	36	Α
Forward voltage	V _{SD}	I _F = 4.5 A, V _{GS} = 0 V		-	0.77	1.2	V
Body diode reverse recovery time	t _{rr}	I _F = 2 A, di/dt = 100 A/μs		-	11	22	ns
Body diode reverse recovery charge	Q _{rr}			-	3.7	8	nC
Reverse recovery fall time	ta			-	6	-	
Reverse recovery rise time	t _b	1		-	5	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-0.64	-	Α

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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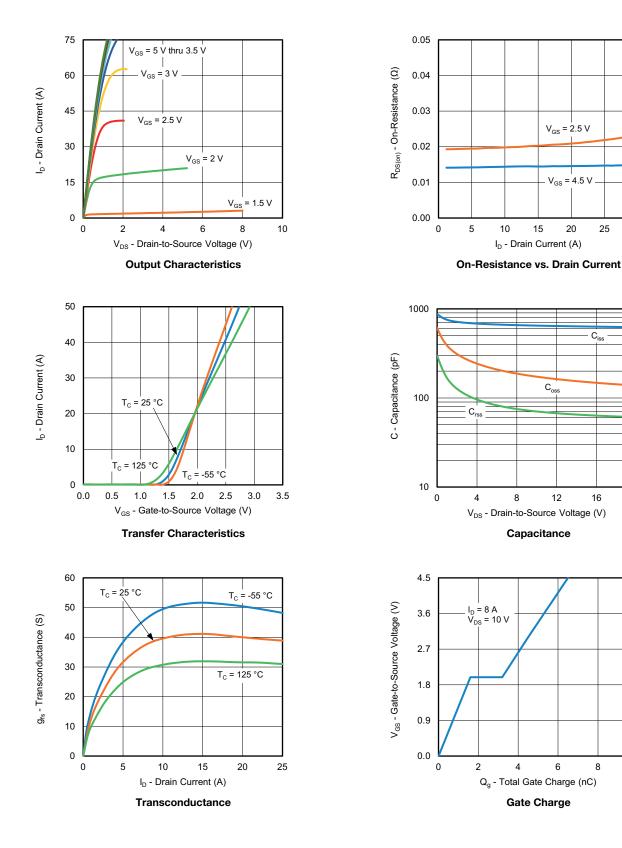
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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



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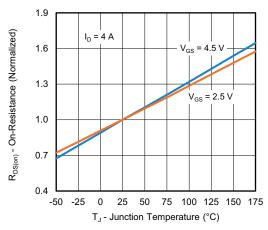
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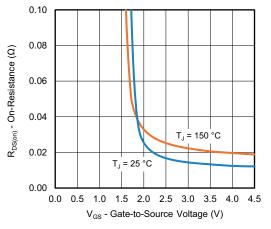


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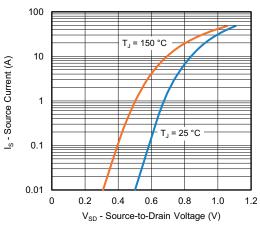
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



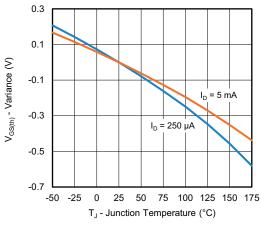
On-Resistance vs. Junction Temperature



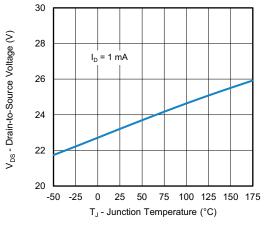
On-Resistance vs. Gate-to-Source Voltage



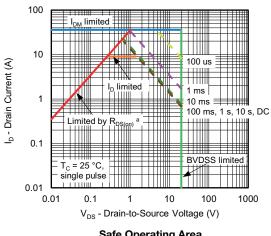
Source Drain Diode Forward Voltage



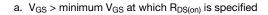
Threshold Voltage



Drain Source Breakdown vs. Junction Temperature



Safe Operating Area



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Note

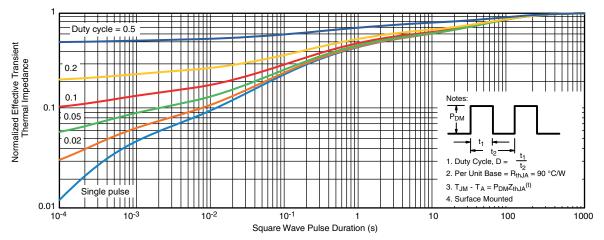
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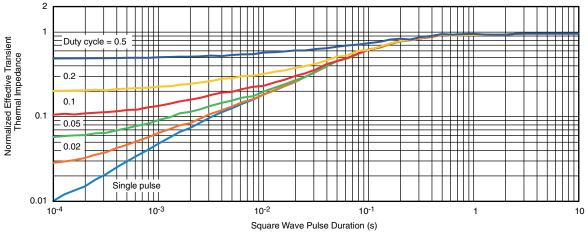


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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63074.

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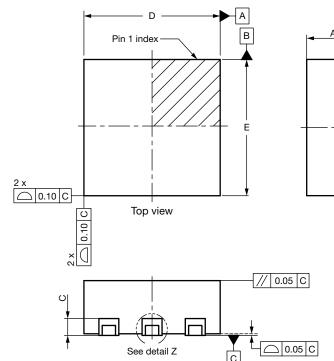
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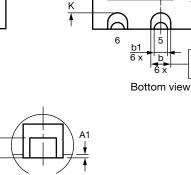
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0.1 M C A B

0.05 🕅 C

PowerPAK[®] SC70W-6L SIDEWETTABLE





Detail Z (2:1)

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E1

DIM	MILLIMETERS			INCHES		
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
А	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.02	0.05	0.000	0.001	0.002
A2	0.10	-	-	0.004	-	-
b	0.25	0.30	0.35	0.010	0.012	0.014
b1	0.15	0.20	0.23	0.006	0.008	0.009
С	0.20	0.25	0.30	0.008	0.010	0.012
D	1.95	2.05	2.15	0.077	0.081	0.085
D1	0.88	0.98	1.08	0.035	0.039	0.043
D2	0.20	0.25	0.30	0.008	0.010	0.012
E	1.95	2.05	2.15	0.077	0.081	0.085
E1	1.06	1.16	1.26	0.042	0.046	0.050
E2	0.82	0.87	0.92	0.032	0.034	0.036
е		0.65 BSC	•	0.026 BSC		
e1		1.30 BSC			0.051 BSC	
K		0.20 typ.		0.008 typ.		
K1		0.47 typ.		0.019 typ.		
K2		0.23 typ.			0.009 typ.	
K3		0.18 typ.		0.003 typ.		
K4		0.35 typ.		0.014 typ.		
K5		0.35 typ.		0.014 typ.		
K6		0.38 typ.			0.015 typ.	
L	0.15	0.25	0.35	0.006	0.010	0.014
L1	-	0.10	-	-	0.004	-
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Notes

Package outline exclusive of mold flash and metal burr

Package outline inclusive of plating .

Revison: 10-Jan-2020



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